查询ER1600FCT供应商

POWER SEMICONDUCTORS

ER1600FCT – ER1606FCT

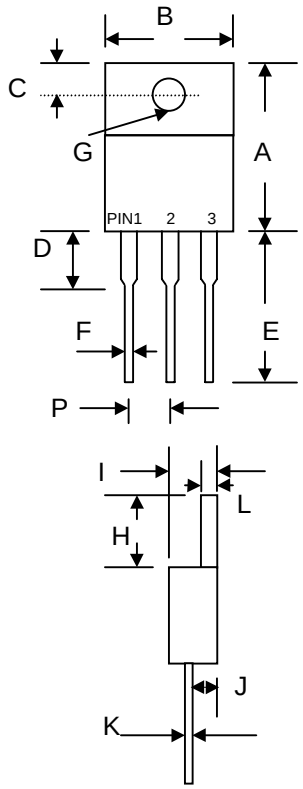
16A ISOLATION SUPER-FAST GLASS PASSIVATED RECTIFIER

Features

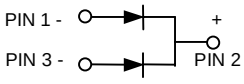
- Glass Passivated Die Construction
- Super-Fast Switching for High Efficiency
- High Current Capability
- Low Reverse Leakage Current
- High Surge Current Capability
- Plastic Material has UL Flammability Classification 94V-O

Mechanical Data

- Case: ITO-220 Full Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: See Diagram
- Weight: 2.24 grams (approx.)
- Mounting Position: Any
- Marking: Type Number



ITO-220		
Dim	**Min**	**Max**
A	14.9	15.1
B	—	10.5
C	2.62	2.87
D	3.56	4.06
E	13.46	14.22
F	0.68	0.94
G	3.74 Ø	3.91 Ø
H	5.84	6.86
I	4.44	4.70
J	2.54	2.79
K	0.35	0.64
L	1.14	1.40
P	2.41	2.67
All Dimensions in mm		



Maximum Ratings and Electrical Characteristics @T_A=25°C unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

Characteristic	Symbol	ER 1600FCT	ER 1601FCT	ER 1601AFCT	ER 1602FCT	ER 1603FCT	ER 1604FCT	ER 1606FCT	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	50	100	150	200	300	400	600	V
RMS Reverse Voltage	$V_{R(RMS)}$	35	70	105	140	210	280	420	V
Average Rectified Output Current @T_C = 105°C	I_O	16							A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	125							A
Forward Voltage @I_F = 8.0A	V_{FM}	0.95				1.3		1.7	V
Peak Reverse Current @T_A = 25°C At Rated DC Blocking Voltage @T_A = 100°C	I_{RM}	10 500							μA
Reverse Recovery Time (Note 1)	t_{rr}	35				50			nS
Typical Junction Capacitance (Note 2)	C_j	80				60			pF
Operating and Storage Temperature Range	T_j, T_{STG}	-65 to +150							°C

Note: 1. Measured with IF = 0.5A, IR = 1.0A, IRR = 0.25A.
2. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.

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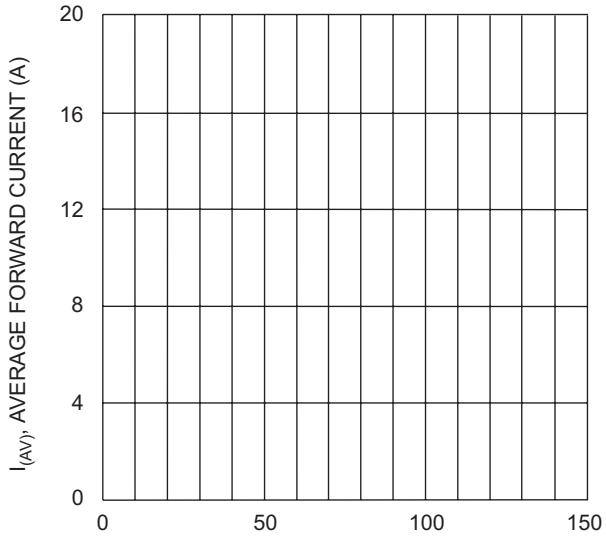


Fig. 1 Forward Current Derating Curve

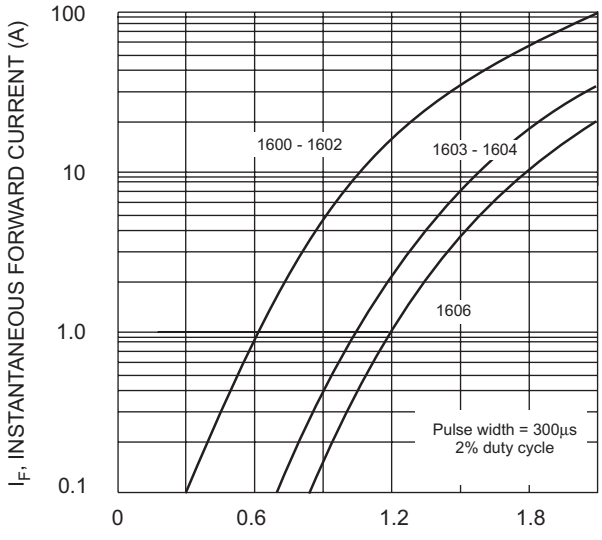


Fig. 2 Typical Forward Characteristics

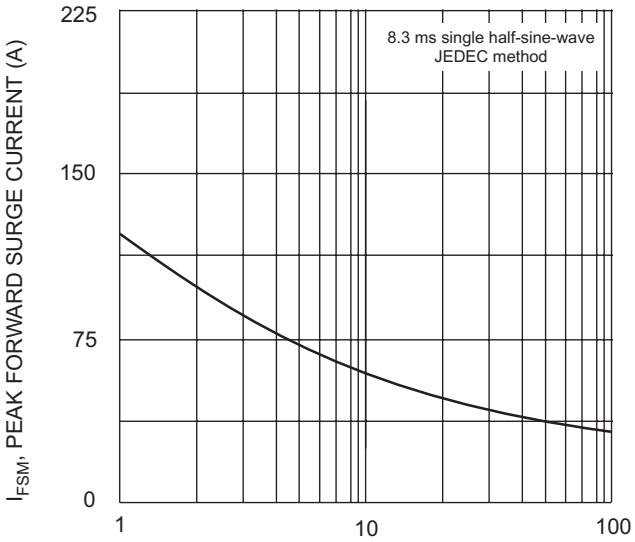


Fig. 3 Maximum Non-Repetitive Surge Current

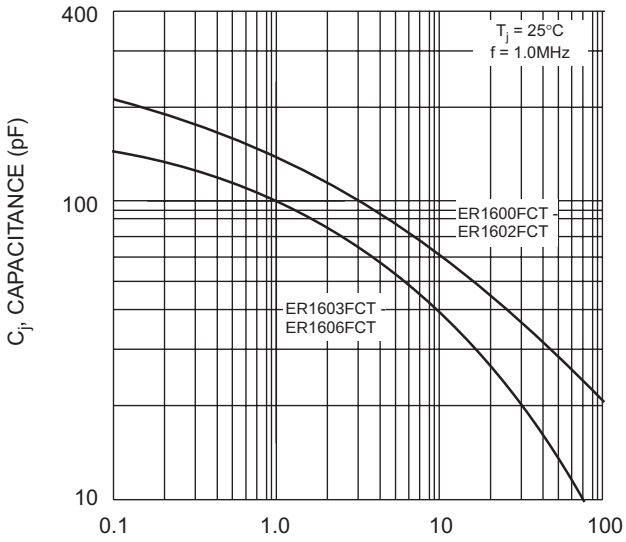
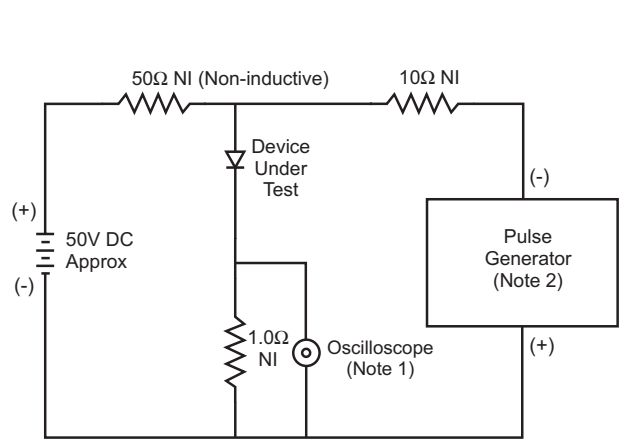


Fig. 4 Typical Junction Capacitance



Notes:
1. Rise Time = 7.0ns max. Input Impedance = 1.0MΩ, 22pF.
2. Rise Time = 10ns max. Input Impedance = 50Ω.

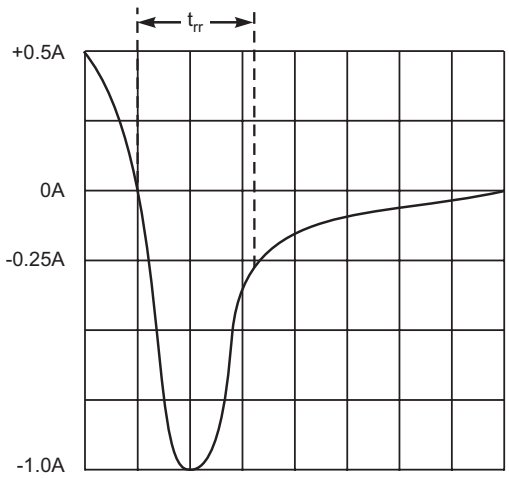


Fig. 5 Reverse Recovery Time Characteristic and Test Circuit

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ORDERING INFORMATION

Product No.	Package Type	Shipping Quantity
ER1600FCT	ITO-220	50 Units/Tube
ER1601FCT	ITO-220	50 Units/Tube
ER1601AFCT	ITO-220	50 Units/Tube
ER1602FCT	ITO-220	50 Units/Tube
ER1603FCT	ITO-220	50 Units/Tube
ER1604FCT	ITO-220	50 Units/Tube
ER1606FCT	ITO-220	50 Units/Tube

Shipping quantity given is for minimum packing quantity only. For minimum order quantity, please consult the Sales Department.

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WARNING: DO NOT USE IN LIFE SUPPORT EQUIPMENT. WTE power semiconductor products are not authorized for use as critical components in life support devices or systems without the express written approval.

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